

# IPW60R099P6XKSA1

## IPW60R099P6XKSA1 Information

www.heirente.com	 IPW60R099P6XKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 600V TO247-3 TO-247-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# IPW60R099P6XKSA1 Specifications

Manufacturer Part Number	IPW60R099P6XKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	CoolMOS? P6
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	37.9A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 1.21mA
Gate Charge (Qg) (Max) @ Vgs	70nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3330pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	278W (Tc)
Rds On (Max) @ Id, Vgs	99 mOhm @ 14.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO247-3
Package / Case	TO-247-3
	Report errors?

### IPW60R099P6XKSA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### IPW60R099P6XKSA1 Payment Methods



If you have any question about IPW60R099P6XKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com